Chip Resistor Array

Type: **EXB1**: 0201 Array

EXB2: 0402 Array

EXB3: 0603 Array EXBN: 0402 Array EXBV: 0603 Array

EXBS: 0805 Array

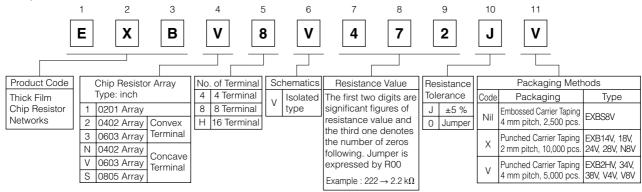
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■ Features

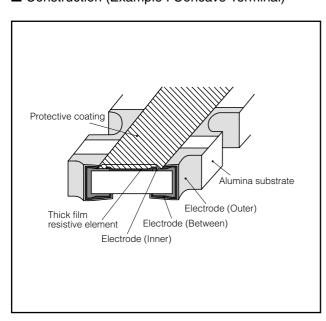
- High density
 - 2 resistors in 0.8 mm \times 0.6 mm size (EXB14V)
 - 4 resistors in 1.4 mm × 0.6 mm size (EXB18V)
 - 2 resistors in 1.0 mm × 1.0 mm size (EXB24V)
 - 4 resistors in 2.0 mm × 1.0 mm size (EXB28V, N8V)
 - 8 resistors in 3.8 mm × 1.6 mm size (EXB2HV)
 - 2 resistors in 1.6 mm × 1.6 mm size (EXB34V, V4V)
 - 4 resistors in 3.2 mm × 1.6 mm size (EXB38V, V8V)
 - 4 resistors in 5.1 mm × 2.2 mm size (EXBS8V)
- Improvement of placement efficiency
 Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard···IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- RoHS compliant

■ Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions Please see Data Files

■ Explanation of Part Numbers

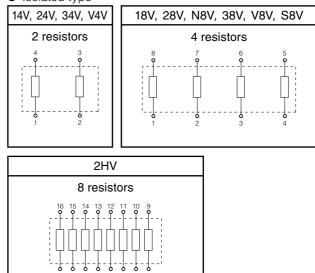


■ Construction (Example : Concave Terminal)



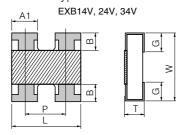
Schematics

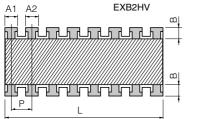
Isolated type

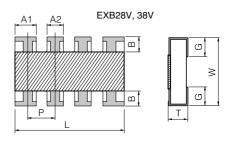


■ Dimensions in mm (not to scale)

(1) Convex Terminal type







Туре	Dimensions (mm)								
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXB14V (0201×2)	0.80 ^{±0.10}	0.60 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	_	0.15 ^{±0.10}	(0.50)	0.15 ^{±0.10}	0.5
EXB24V (0402×2)	1.00 ^{±0.10}	1.00 ^{±0.10}	0.35 ^{±0.10}	0.40 ^{±0.10}	_	0.18 ^{±0.10}	(0.65)	0.25 ^{±0.10}	1.2
EXB28V (0402×4)	$2.00^{\pm0.10}$	1.00 ^{±0.10}	0.35 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.20 ^{±0.10}	(0.50)	0.25 ^{±0.10}	2.0
EXB2HV (0402×8)	$3.80^{\pm0.10}$	1.60 ^{±0.10}	0.45 ^{±0.10}	0.35 ^{±0.10}	0.35 ^{±0.10}	0.30 ^{±0.10}	(0.50)	0.30 ^{±0.10}	9.0
EXB34V (0603×2)	1.60 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	_	0.30 ^{±0.20}	(0.80)	0.30 ^{±0.20}	3.5
EXB38V (0603×4)	3.20 ^{±0.20}	1.60 ^{±0.15}	0.50 ^{±0.10}	0.65 ^{±0.15}	0.45 ^{±0.15}	0.30 ^{±0.20}	(0.80)	0.35 ^{±0.20}	7.0

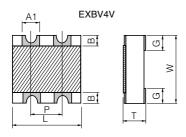
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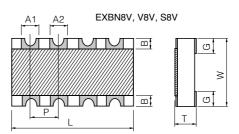
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(2) Concave Terminal type

() Reference

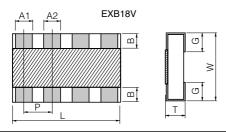




Туре	Dimensions (mm)								Mass (Weight)
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXBN8V (0402×4)	2.00 ^{±0.10}	1.00 ^{±0.10}	0.45 ^{±0.10}	0.30 ^{±0.10}	0.30 ^{±0.10}	0.20 ^{±0.15}	(0.50)	0.30 ^{±0.15}	3.0
EXBV4V (0603×2)	$1.60^{+0.20}_{-0.10}$	1.60+0.20	0.60 ^{±0.10}	0.60 ^{±0.10}	_	0.30 ^{±0.15}	(0.80)	0.45 ^{±0.15}	5.0
EXBV8V (0603×4)	$3.20^{+0.20}_{-0.10}$	1.60+0.20	0.60 ^{±0.10}	0.60 ^{±0.10}	0.60 ^{±0.10}	0.30 ^{±0.15}	(0.80)	0.45 ^{±0.15}	10
EXBS8V (0805×4)	5.08+0.20 -0.10	2.20+0.20 -0.10	0.70 ^{±0.20}	0.80 ^{±0.15}	0.80 ^{±0.15}	0.50 ^{±0.15}	(1.27)	0.55 ^{±0.15}	30

(3) Flat Terminal type

() Reference



Type	Dimensions (mm)								Mass (Weight)
(inch size)	L	W	Т	A1	A2	В	Р	G	[g/1000 pcs.]
EXB18V (0201×4)	1.40 ^{±0.10}	0.60 ^{±0.10}	0.35 ^{±0.10}	0.20 ^{±0.10}	0.20 ^{±0.10}	0.10 ^{±0.10}	(0.40)	0.20 ^{±0.10}	1.0

() Reference

■ Ratings

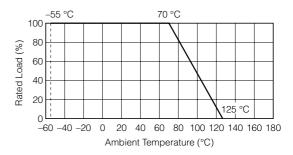
Ite	Specifications			
Resistance Range	10 Ω to 1 M Ω : E24 series			
Resistance Toleran	J:±5 %			
	14V,24V,V4V,34V	4 terminal		
Number of Terminals	18V,28V,N8V,38V,V8V,S8V	8 terminal		
	2HV	16 terminal		
	14V,24V,V4V,34V	2 element		
Number of Resistors	18V,28V,N8V,38V,V8V,S8V	4 element		
	2HV	8 element		
	14V,N8V	0.031 W/element		
	18V	0.031 W/element (0.1 W/package)		
Power Rating at 70 °C	24V,28V,V4V,34V,V8V,38V	0.063 W/element		
	S8V	0.1 W/element		
	2HV	0.063 W/element (0.25 W/package)		

	I	Specifications			
		14V,18V	12.5 V		
Limiting Element Voltage ⁽¹⁾		2HV	25 V		
		24V,28V,N8V,38V,34V,V4V,V8V	50 V		
		S8V	100 V		
		14V,18V	25 V		
Maximum Overload Voltage (2)		2HV	50 V		
		24V,28V,N8V,38V,34V,V4V,V8V	100 V		
		S8V	200 V		
T.C.F	R.		±200×10 ⁻⁶ /°C		
Cate	gory Temperatu	ure Range	−55 °C to 125 °C		
		14V,18V	0.5 A		
ray	Rated Current	2HV,24V,28V,N8V,38V,34V,V4V,V8V	1 A		
An		S8V	2 A		
Jumper Array	м : О : .	14V,18V	1 A		
Jur	Maximum Overload Current	2HV,24V,28V,N8V,38V,34V,V4V,V8V	2 A		
	Ouriont	S8V	4 A		

⁽¹⁾ Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

Power Derating Curve

For resistors operated in ambient temperature above 70 °C, power rating shall be derated in accordance with the figure on the right.



⁽²⁾ Overload (Short-time Overload) Test Voltage (SOTV) shall be determined from SOTV=2.5 × Power Rating or max. Overload Voltage listed above whichever less.